



Non-Volatile Neural Network Accelerator in Your SoC

Sang-Soo Lee, CEO and Co-Founder Seung-Hwan Song, CTO and Co-Founder ANAFLASH Inc.



Company Overview





WHAT WE DO?

Founded in 2017 we develop Logic Compatible NV-DNN and eFlash IPs for Edge Computing



TEAM Executives have

combined 60+ years of Engineering & Management Experience



TECHNOLOGY Patent pending NV-DNN and eFlash IPs in Standard CMOS process



WHERE WE ARE?

Headquartered in San Jose CA USA





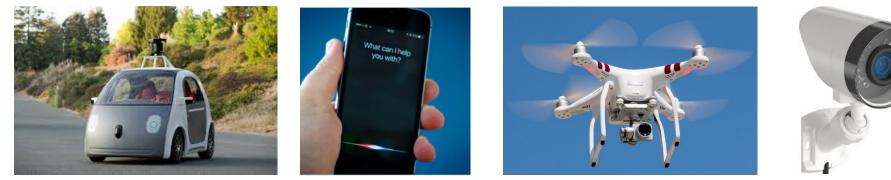




Berkeley S K Y \supset E C K

Artificial Intelligence in the Edge



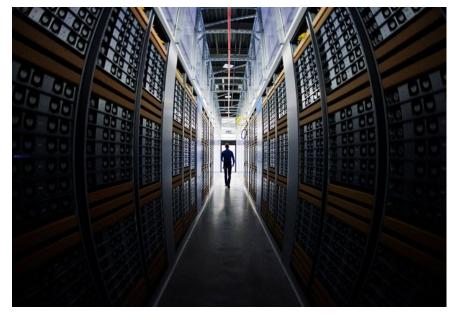






Growing Cloud Energy Concern

9,000 terawatt hours (TWh)



N. Jones (Nature 2018)

20.9% of projected ENERGY FORECAST electricity demand Widely cited forecasts suggest that the total electricity demand of information and communications technology (ICT) will accelerate in the 2020s, and that data centres will take a larger slice. Networks (wireless and wired) Production of ICT Consumer devices (televisions, computers, mobile phones) Data centres 2010 2012 2014 2016 2018 2020 2022 2024 2026 2028 2030

Flash Memory Summit



Let's move to Edge! However,...

- Challenges in the Edge Environment
 - Size, Weight, and Power (SWaP) limited
 - Compute and memory resource limited
 - Cost sensitive

How to make it work under these challenges?



- Technique that allows approximate results in applications not requiring strict accuracy
- This can improve power efficiency a lot
- In case, such errors can be managed by system level techniques statistically (i.e. ECC and redundancy, etc.)
- Could be combined with Digital (However,...)



Analog vs. Digital Computation

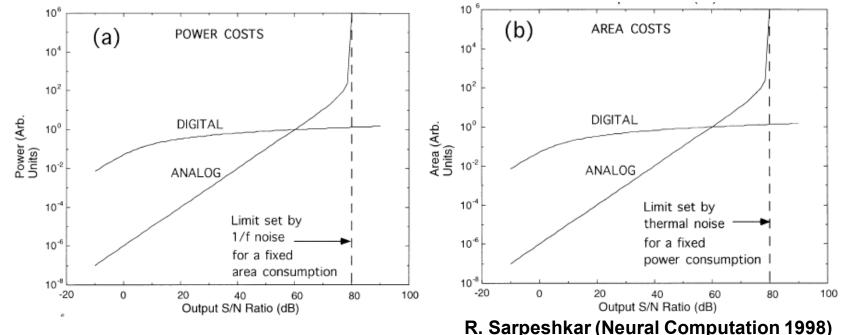
ANALOG	DIGITAL	Which is better for efficiency?
Narrow signal swing	Full VDD-GND swing	ANALOG
Information from single transistor (continuous)	Information from single transistor (1 or 0)	ANALOG
Multi-bit single wire	Single-bit single-wire	ANALOG
Result affected by noise and variation	High noise margin	DIGITAL

R. Sarpeshkar (Neural Computation 1998)

• Analog has more advantages for efficiency!

Let's do Analog Computing in Edge



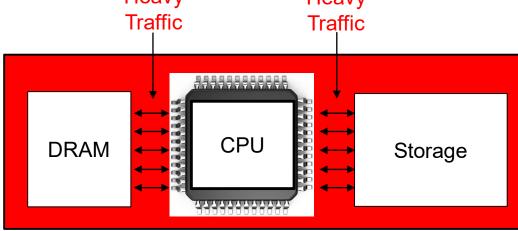


Analog is significantly efficient at low-precision!



Memory Access Bottleneck

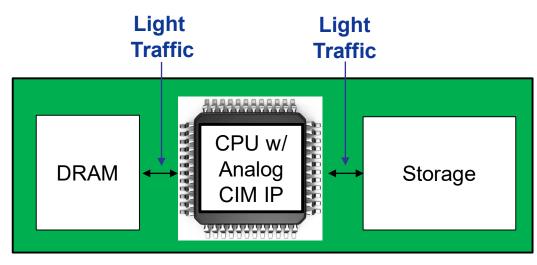
 Off-chip access from CPU to memory (storage) has long (and unpredictable) latency, and limited bandwidth
 Heavy





Analog CIM Architecture

- Analog Compute-in-Memory IP integrated in CPU
- Reduce off-chip memory access





Lesson Learning from Human Brain

- Brain has much more efficiency with much small values of SWaP
 - 3.6×10^{15} synaptic operation with $12W \rightarrow 3 \times 10^{14}$
 - i9 CPU running 3GHz with 140W \rightarrow 2x10⁷

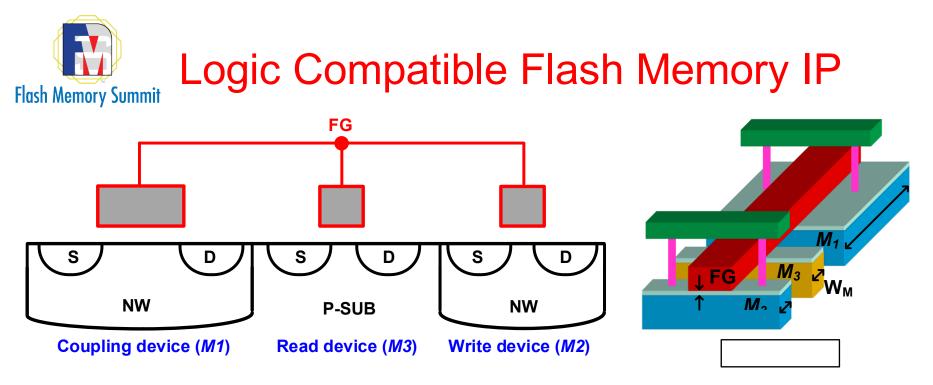
 Biological neural network doesn't discriminate computational device and memory device



Candidates for Analog Computing

- Logic gates (e.g. NAND, XOR, etc.) \rightarrow No
- Transistor, capacitor, inductor, etc. \rightarrow Yes

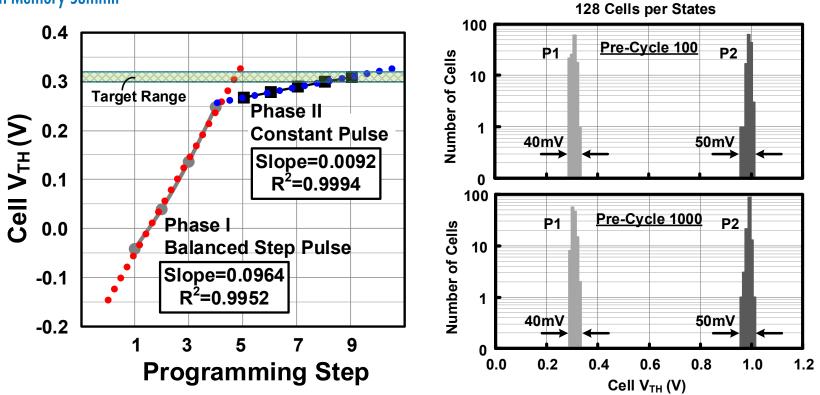
- SRAM (Not able to store multi-bit, volatile) \rightarrow No
- MRAM (Not able to store multi-bit, non-volatile) \rightarrow No
- ReRAM (multi-bit, nonvolatile) → Yes
- Flash (multi-bit, nonvolatile) \rightarrow Yes



No Process Overhead in Standard Logic Process Leverage High Performance Digital Logic (Scalable)

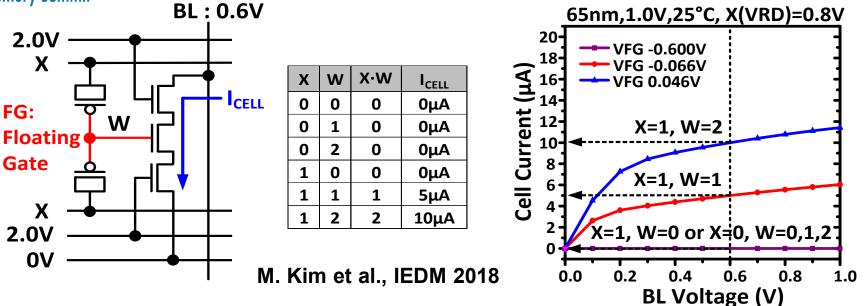


Precise Analog Programming Scheme



Logic Compatible Flash Based Synapse

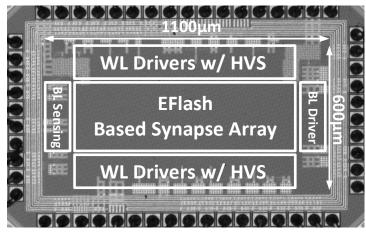




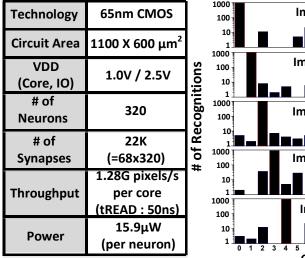
Cell current proportional to X·W (=0µA,5µA,10µA)

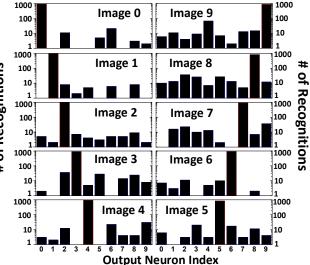


65nm Test Chip Summary



M. Kim et al., IEDM 2018





High efficiency (171.1 TOPS/W) by analog CIM arch. Recognition accuracy close to the SW model Flash Memory Summit 2019 Santa Clara, CA



- Growing need to move AI computing toward Edge
- Analog computing can improve power efficiency by approximately computing neural network
- Analog computing-in-memory using logic compatible embedded Flash memory is a strong candidate to overcome memory bottleneck
- Test chip result fabricated in 65nm logic process shows power efficiency of 171.1 TOPS/W



THANK YOU FOR YOUR ATTENTION



info@anaflash.com



Always-on Local AI and NVM solution For Battery-Powered Smart Devices

3003 N. First St. #221 San Jose, CA 95134